TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LVX240F,TC74LVX240FW,TC74LVX240FT TC74LVX244F,TC74LVX244FW,TC74LVX244FT

Octal Bus Buffer

TC74LVX240 Inverted, 3-State Outputs
TC74LVX244 Non-Inverted, 3-State Outputs

The TC74LVX240,244F/ FW/ FT is a high-speed CMOS OCTAL BUS BUFFER fabricated using silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation. This device is suitable for low-voltage and battery operated systems.

The TC74LVX240 is an inverting 3-state buffer while the TC74LVX244 is non-inverting. Both devices have two active-low output enables. These devices are designed to be used in such applications as 3-state memory address drivers.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

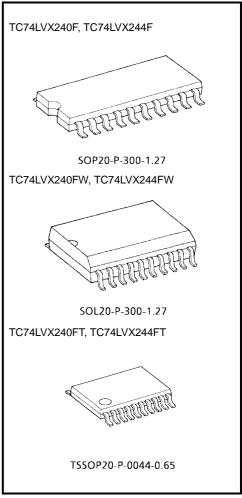
#### **Features**

- High-speed:  $t_{pd} = 4.7 \text{ ns (typ.)} (V_{CC} = 3.3 \text{ V})$
- Low power dissipation:  $ICC = 4 \mu A \text{ (max)} \text{ (Ta} = 25^{\circ}\text{C)}$
- Input voltage level:  $V_{IL} = 0.8 \text{ V (max)} (V_{CC} = 3 \text{ V})$

 $V_{IH} = 2.0 \text{ V (min) (V}_{CC} = 3 \text{ V)}$ 

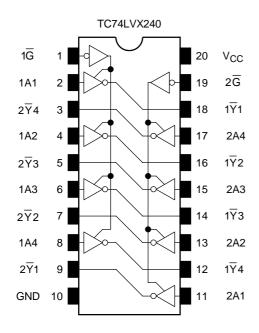
- Power-down protection provided on all inputs
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Low niose: VOLP = 0.8 V (max)
- Pin and function compatible with 74HC240/244

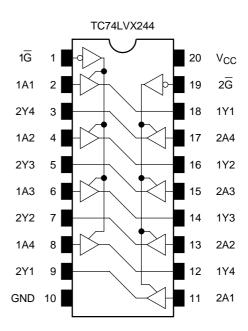
Note: xxxFW (JEDEC SOP) is not available in



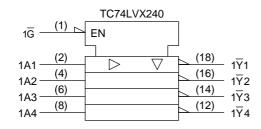
Weight SOP20-P-300-1.27: 0.22 g (typ.) SOL20-P-300-1.27: 0.46 g (typ.) TSSOP20-P-0044-0.65: 0.08 g (typ.)

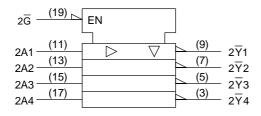
#### Pin Assignment (top view)

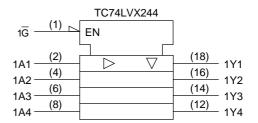


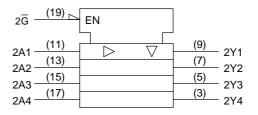


#### **IEC Logic Symbol**









#### **Truth Table**

Inp	uts	Outputs				
G	A <sub>n</sub>	Y <sub>n (244)</sub>	<u>Y</u> n(240)			
L	L	L	Н			
L	Н	Н	L			
Н	Х	Z	Z			

X: Don't care

Z: High impedance



# **Maximum Ratings**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	$-0.5$ to $V_{CC} + 0.5$	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

# **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 3.6	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

## **Electrical Characteristics**

#### **DC Characteristics**

Characteristics		Sym- bol			Ta = 25°C			Ta = -40 to 85°C		Unit	
				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max		
H-level V <sub>IH</sub>				2.0	1.5	_	_	1.5	_		
		V <sub>IH</sub>	_		3.0	2.0	_	_	2.0		_
Input voltage					3.6	2.4	_	_	2.4	_	V
input voitage							_	0.5		0.5	v
	L-level	VIL	_		3.0	_	_	0.8	_	0.8	
						_	_	0.8	_	0.8	
				$I_{OH} = -50 \ \mu A$	2.0	1.9	2.0	_	1.9	_	
H-leve	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -50 \ \mu A$	3.0	2.9	3.0	_	2.9	_	
Output voltage				$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_	V
Output voltage			V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 50 \mu A$	2.0	_	0	0.1	_	0.1	V
	L-level	V <sub>OL</sub>		$I_{OL} = 50 \mu A$	3.0	_	0	0.1		0.1	
			$I_{OL} = 4 \text{ mA}$	3.0		_	0.36		0.44		
3-State output		loz	$V_{IN} = V_{IH}$ or $V_{IL}$		3.6			±0.25		±2.5	μА
Off-state current		loz	$V_{OUT} = V_{CC}$ or GND		5.0			±0.23		±2.3	μΑ
Input leakage curre	nt	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		3.6		_	±0.1		±1.0	μΑ
Quiescent supply co	urrent	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		3.6	_	_	4.0	_	40.0	μΑ

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## AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	st Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max	
	t <sub>pLH</sub>		2.7	15		5.7	10.1	1.0	12.5	ns
Propagation delay time				50		8.2	13.6	1.0	16.0	
(TC74LVX240)	<b>+</b>		$3.3 \pm 0.3$	15		4.3	6.2	1.0	7.5	113
	t <sub>pHL</sub>		3.3 ± 0.3	50		6.8	9.7	1.0	11.0	
	t-111		2.7	15		6.1	11.4	1.0	13.5	- ns
Propagation delay time	t <sub>pLH</sub>		2.7	50		8.6	14.9	1.0	17.0	
(TC74LVX244)	t <sub>pHL</sub>	_	3.3 ± 0.3	15		4.7	7.1	1.0	8.5	
				50		7.2	10.6	1.0	12.0	
	t <sub>pZL</sub>	$R_L = 1 \text{ k}\Omega$	2.7	15		7.1	13.8	1.0	16.5	ns
Output enable time				50		9.6	17.3	1.0	20.0	
Output enable time	t <sub>pZH</sub>		3.3 ± 0.3	15		5.5	8.8	1.0	10.5	
				50		8.0	12.3	1.0	14.0	
Output disable time	t <sub>pLZ</sub>	$t_{pLZ}$ $R_L = 1 k\Omega$	2.7	50		11.6	16.0	1.0	19.0	ns
Output disable time	t <sub>pHZ</sub>		$3.3 \pm 0.3$	50		9.7	11.4	1.0	13.0	113
Output to output skew	t <sub>osLH</sub>	(Note 1)	2.7	50		_	1.5	_	1.5	ns
Output to output skew	t <sub>osHL</sub>	(Note 1)	$3.3 \pm 0.3$	50	_	_	1.5	_	1.5	115
Input capacitance	C <sub>IN</sub>			(Note 2)		4	10	_	10	pF
Output capacitance	C <sub>OUT</sub>					6		_		pF
Power dissipation capacitance	C	TC74LVX240			_	17	_	_		pF
(Note 3)	C <sub>PD</sub>	TC74LVX244				19	_	_		þΓ

Note 1: Parameter guaranteed by design.  $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$ 

Note 2: Parameter guaranteed by design.

Note 3: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

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Average operating current can be obtained by the equation:

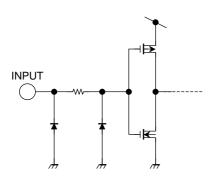
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$ 



# Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

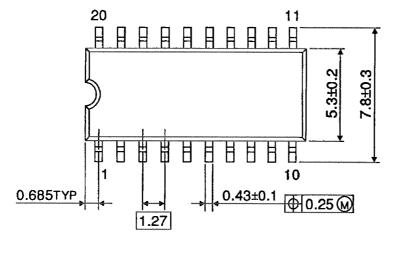
Characteristics		Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic	$V_{OL}$	$V_{OLP}$	_	3.3	0.5	0.8	V
Quiet output minimum dynamic	$V_{OL}$	$V_{OLV}$	_	3.3	-0.5	-0.8	V
Minimum high level dynamic input voltage	V <sub>IH</sub>	V <sub>IHD</sub>	_	3.3	_	2.0	V
Maximum low level dynamic input voltage	$V_{IL}$	V <sub>ILD</sub>	_	3.3	_	0.8	V

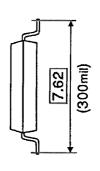
# **Input Equivalent Circuit**

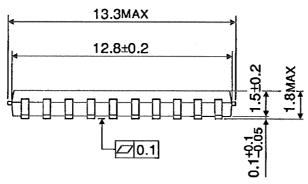


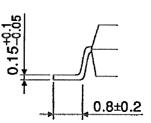
# **Package Dimensions**

SOP20-P-300-1.27 Unit: mm







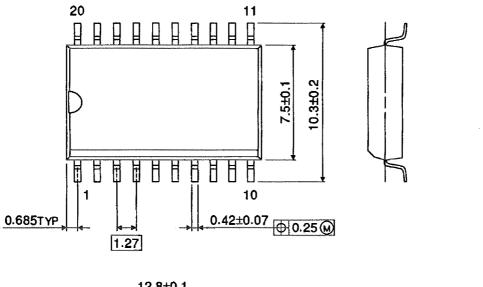


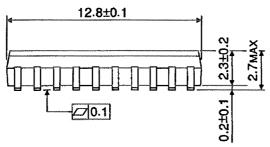
Weight: 0.22 g (typ.)

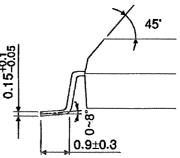
Unit: mm

# **Package Dimensions**

SOL20-P-300-1.27





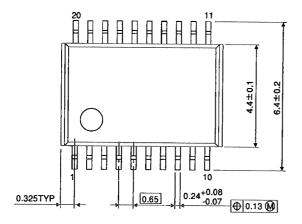


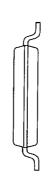
Weight: 0.46 g (typ.)

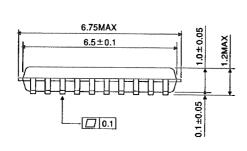
Unit: mm

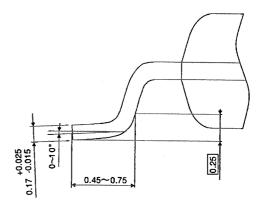
# **Package Dimensions**

#### TSSOP20-P-0044-0.65









Weight: 0.08 g (typ.)

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